

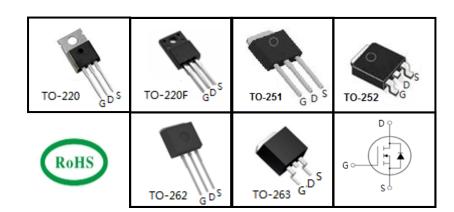
# **650V Super-Junction Power MOSFET**

#### **FEATURES**

- Very low FOM R<sub>DS(on)</sub> × Q<sub>g</sub>
- 100% avalanche tested
- RoHS compliant

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



Device Marking and Package Information						
Device	TPP65R380C	TPA65R380C	TPU65R380C	TPD65R380C	TPC65R380C	TPB65R380C
Package	TO-220	TO-220F	TO-251	TO-252	TO-262	TO-263
Marking	65R380C	65R380C	65R380C	65R380C	65R380C	65R380C

<b>Absolute Maximum Ratings</b> T <sub>C</sub> = 25°C, unless otherwise noted					
Parameter			Value		Unit
		Symbol	TO-220,TO-251,TO-252 TO-262,TO-263		
Drain-Source Voltage (V <sub>GS</sub> = 0V)		V <sub>DSS</sub>	650		V
Continuous Drain Current		I <sub>D</sub>	11		А
Pulsed Drain Current	(note1)	I <sub>DM</sub>	33		А
Gate-Source Voltage		$V_{GSS}$	±30		V
Single Pulse Avalanche Energy	(note2)	E <sub>AS</sub>	211		mJ
Avalanche Current	(note1)	I <sub>AR</sub>	1.6		А
Repetitive Avalanche Energy	(note1)	E <sub>AR</sub>	0.32		mJ
Power Dissipation (T <sub>C</sub> = 25°C)		P <sub>D</sub>	78	31.3	W
Operating Junction and Storage Tempe	erature Range	T <sub>J</sub> , T <sub>stg</sub>	-55~+150		°C

Thermal Resistance						
		Value				
Parameter	Symbol	TO-220,TO-251,TO-252 TO-262,TO-263	TO-220F	Unit		
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	1.6	4	°C/W		
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62	80	°C/VV		

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#### TPP65R380C, TPA65R380C, TPU65R380C, TPD65R380C, TPC65R380C, TPB65R380C

#### Wuxi Unigroup Microelectronics Company

<b>Specifications</b> $T_J = 25^{\circ}C$ , ur	11622 01116	rwise floted I					
Parameter	Symbol Test (	Test Conditions	Value			Unit	
			Min.	Тур.	Max.		
Static							
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_{D} = 250\mu A$	650			V	
Zero Gate Voltage Drain Current	1	$V_{DS} = 650V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1		
Zero Gate Voltage Drain Guirent	I <sub>DSS</sub>	$V_{DS} = 650V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100	μA	
Gate-Source Leakage	$I_{\rm GSS}$	$V_{GS} = \pm 30V$			±100	nA	
Gate-Source Threshold Voltage	$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4	>	
Drain-Source On-Resistance (Note3)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 5.5A$		0.34	0.38	Ω	
Forward Transconductance (Note3)	$g_{fs}$	$V_{DS} = 10V, I_{D} = 5.5A$		7.8		S	
Dynamic							
Input Capacitance	C <sub>iss</sub>	$V_{GS} = 0V$ ,		901		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 50V$ ,		50			
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		5.5			
Total Gate Charge	$Q_g$			21		nC	
Gate-Source Charge	$Q_{gs}$	$V_{DD} = 520V, I_{D} = 11A,$ $V_{GS} = 10V$		4.5			
Gate-Drain Charge	$Q_{gd}$	65		7			
Turn-on Delay Time	t <sub>d(on)</sub>			41			
Turn-on Rise Time	t <sub>r</sub>	$V_{DD} = 400V, I_{D} = 11A,$		20			
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 25\Omega$		123		ns	
Turn-off Fall Time	t <sub>f</sub>			6.4			
Drain-Source Body Diode Characteris	stics			•			
Continuous Body Diode Current	I <sub>s</sub>	T 0500			9.2	۸	
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25°C			29	Α	
Body Diode Voltage	V <sub>SD</sub>	$T_J = 25^{\circ}C$ , $I_{SD} = 11A$ , $V_{GS} = 0V$		0.9	1.2	٧	
Reverse Recovery Time	t <sub>rr</sub>			280		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	$V_R = 520V, I_F = I_S,$ $di_F/dt = 100A/\mu s$		2.8		μC	
Peak Reverse Recovery Current	I <sub>rrm</sub>	3. <sub>F</sub> , 3.1 1007 ¢ <b>p</b> 0		17		А	

#### **Notes**

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2.  $I_{AS}$  = 1.6A,  $V_{DD}$  = 50V,  $R_{G}$  = 25 $\Omega$ , Starting  $T_{J}$  = 25 $^{\circ}$ C
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 1%



#### **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted

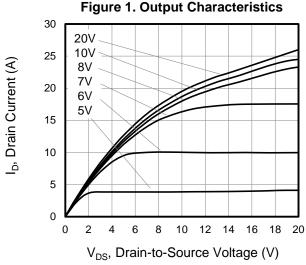
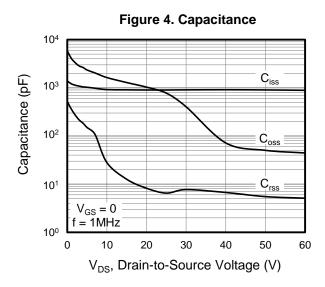
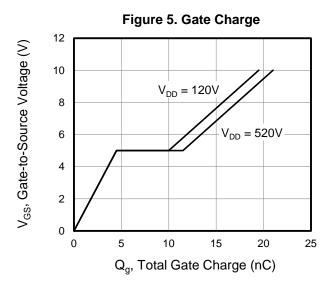
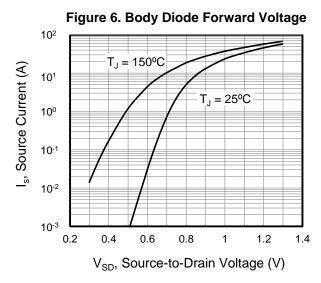


Figure 2. Transfer Characteristics 20  $V_{DS} = 10V$  $T_{\rm J} = 25^{\rm o}{\rm C}$ I<sub>D</sub>, Drain Current (A) 16 12  $T_{J} = 150^{\circ}C$ 8 0 2 6 8 10 0 V<sub>GS</sub>, Gate-to-Source Voltage (V)

Figure 3. On-Resistance vs. Drain Current 0.46  $V_{GS} = 10V$  $R_{DS(on)}$ , On-Resistance  $(\Omega)$  $T_1 = 25^{\circ}C$ 0.4 0.34 0.28 0.22 0.16 15 10 20 I<sub>D</sub>, Drain Current (A)









#### **Typical Characteristics** $T_J = 25^{\circ}\text{C}$ , unless otherwise noted

Figure 7. On-Resistance vs. **Junction Temperature** 3  $V_{GS} = 10V$  $I_{D} = 5.5A$ 2.5 R<sub>DS(on)</sub>, (Normalized) 2 1.5 1 0.5 -100 50 100 150 200

T<sub>J</sub>, Junction Temperature (°C) Figure 9. Transient Thermal Impedance TO-220,TO-262,TO-263,TO-251,TO-252 10¹  $\mathsf{Z}_{\mathsf{thJC}}$ , Thermal Impedance (K/W) 100 10-1 D = 0.5D = 0.2D = 0.1D = 0.0510-2 D = 0.02D = 0.01Single Pulse 10-3

10-6

10-5

10-4

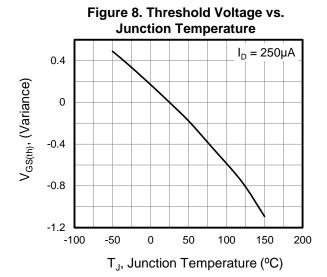
T<sub>p</sub>, Pulse Width (s)

10-3

10-2

10-1

10<sup>-7</sup>



**TO-220F** 10<sup>1</sup>  $\mathsf{Z}_{\mathsf{thJC}},$  Thermal Impedance (K/W) 100 10-1 D = 0.5D = 0.2D = 0.1D = 0.0510-2 D = 0.02D = 0.01Single Pulse 10-3 10-6 10<sup>-5</sup> 10-4  $10^{-3}$   $10^{-2}$   $10^{-1}$   $10^{0}$   $10^{1}$ 10-7

T<sub>p</sub>, Pulse Width (s)

Figure 10. Transient Thermal Impedance

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Figure A: Gate Charge Test Circuit and Waveform

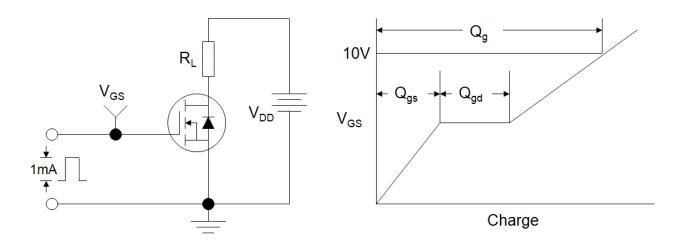


Figure B: Resistive Switching Test Circuit and Waveform

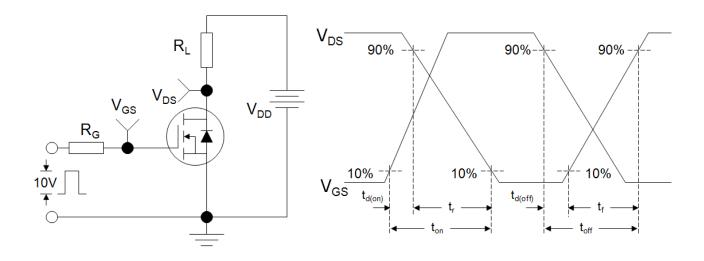
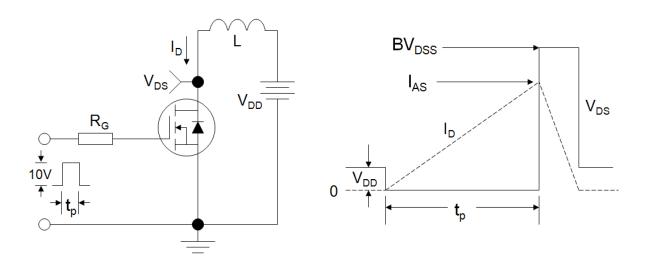


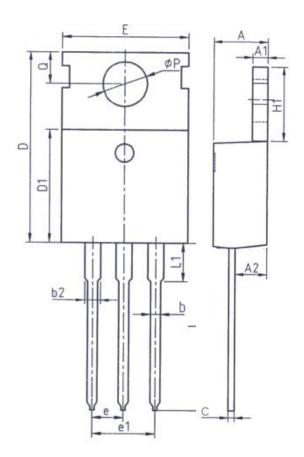
Figure C: Unclamped Inductive Switching Test Circuit and Waveform

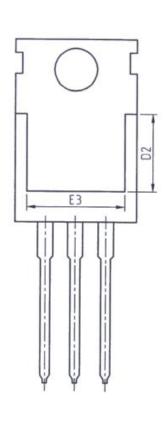


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# **TO-220**

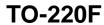


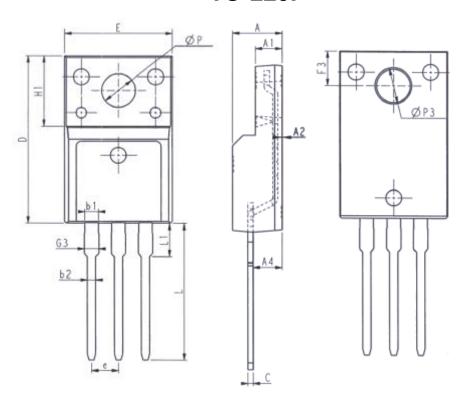


Unit: mm					
Symbol	Min.	Max.			
Α	4. 37	4. 77			
A1	1. 25	1. 45			
A2	2. 20	2. 60			
b	0. 70	0. 95			
b2	1. 17	1. 47			
С	0. 40	0. 65			
D	15. 10	16. 10			
D1	8. 80	9. 40			
D2	5. 50	_			

Unit: mm				
Symbol	Min.	Max.		
E	9. 70	10. 30		
E3	7. 00	ı		
е	2. 54BSC			
e1	5. 08BSC			
H1	6. 25	6. 85		
L	12. 75	13.80		
L1	-	3. 40		
Р	3. 40	3. 80		
Q	2. 60	3. 00		



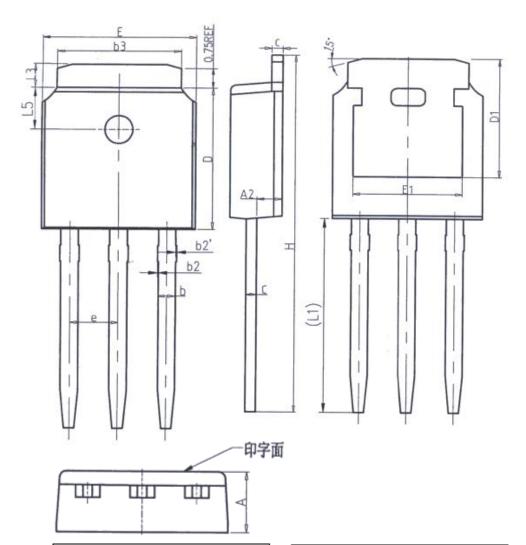




Unit: mm			l	Jnit: mn	1
Symbol	Min.	Max.	Symbol	Min.	Max.
E	9.96	10.36	L	12. 68	13. 28
Α	4. 50	4. 90	L1	2. 93	3. 13
A1	2. 34	2. 74	Р	3. 03	3. 38
A2	0. 30	0.60	Р3	3. 15	3. 65
A4	2. 56	2. 96	F3	3. 15	3. 45
С	0.40	0. 65	G3	1. 25	1. 55
D	15. 57	16. 17	b1	1. 18	1. 43
H1	6. 70	OREF	b2	0. 70	0. 95
е	2. 54	4BSC			



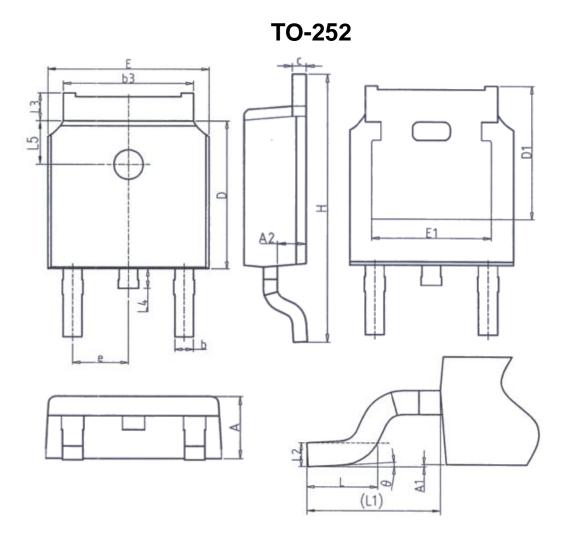
## **TO-251**



Unit: mm				
Symbol	Min.	Max.		
Α	2. 20	2. 40		
A2	0. 97	1. 17		
b	0. 68	0.90		
b2	0.00	0.10		
b2′	0.00	0.10		
b3	5. 20	5. 50		
С	0. 43	0. 63		
D	5. 98	6. 22		

Unit: mm				
Symbol	Min.	Max.		
D1	5. 30REF			
E	6. 40	6. 80		
E1	4. 63	-		
е	2. 286BSC			
Н	16. 22	16. 82		
L1	9. 15	9. 65		
L3	0.88	1. 28		
L5	1. 65	1. 95		

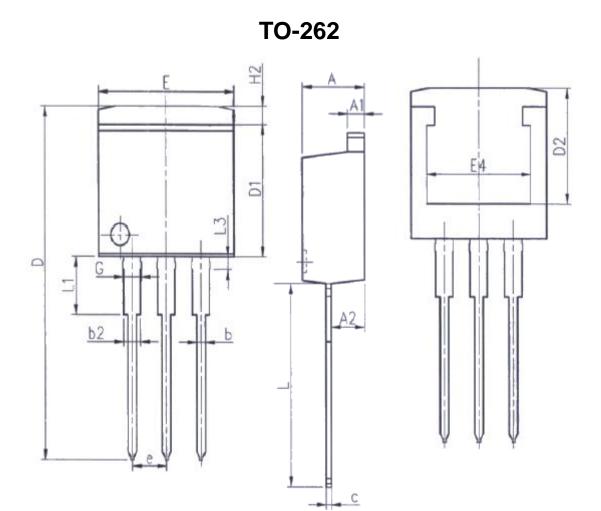




Unit: mm					
Symbol	Min.	Max.			
Α	2. 20	2. 40			
A1	0.00	0. 20			
A2	0. 97	1. 17			
b	0. 68	0. 90			
b3	5. 20	5. 50			
С	0. 43	0. 63			
D	5. 98	6. 22			
D1 5. 30REF					
E	6. 40	6. 80			
E1	4. 63	_			

Unit: mm				
Symbol	Min.	Max.		
е	2. 28	6BSC		
Н	9. 40	10.50		
L	1. 38	1. 75		
L1	2. 90REF			
L2	0. 51	IBSC		
L3	0.88	1. 28		
L4	- 1.00			
L5	1. 65	1. 95		
θ	0°	8°		



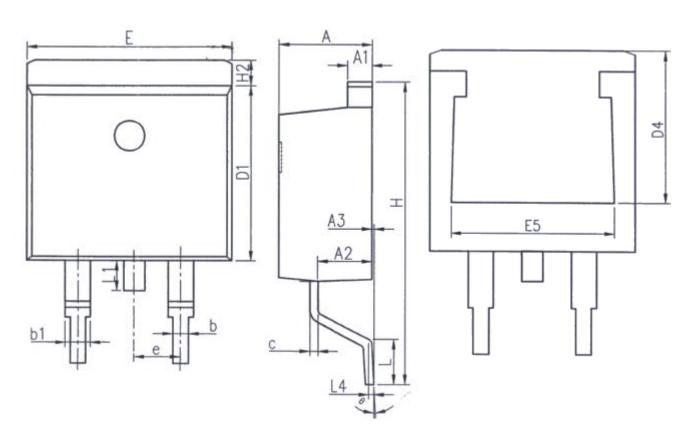


Unit: mm				
Symbol	Min.	Max.		
Α	4. 37	4. 77		
A1	1. 22	1. 42		
A2	2. 47	2. 87		
b	0. 70	0. 97		
b2	1. 17	1. 42		
С	0. 28	0.53		
D	23. 20	24. 02		
D1	8. 38	8. 90		
D2	6. 00	-		

Unit: mm			
Symbol	Min.	Max.	
E	9. 90	10.39	
E4	7. 30	_	
е	2. 54BSC		
G	1. 25	1.50	
H2	ı	1. 31	
L	13. 34	14. 10	
L1	3. 30	4. 06	
L3	0. 95	1. 15	







Unit: mm			
Symbol	Min.	Max.	
Α	4. 37	4. 77	
<b>A</b> 1	1. 22	1. 42	
A2	2. 49	2. 89	
A3	0. 00	0. 25	
b	0. 70	0. 96	
b1	1. 17	1. 47	
С	0. 30	0. 53	
D1	8. 50	8. 90	
D4	6. 60	_	

Unit: mm			
Symbol	Min.	Max.	
E	9.86	10.36	
E5	7. 06	-	
е	2. 54BSC		
Н	14. 70	15. 50	
H2	1. 07	1. 47	
L	2.00	2. 60	
L1	1. 40	1. 70	
L4	0. 25BSC		
θ	0°	9°	



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